

GENERAL PURPOSE SINGLE OPERATIONAL AMPLIFIER

- LARGE INPUT VOLTAGE RANGE
- NO LATCH-UP
- HIGH GAIN
- SHORT-CIRCUIT PROTECTION
- NO FREQUENCY COMPENSATION
- REQUIRED
- SAME PIN CONFIGURATION AS THE UA709

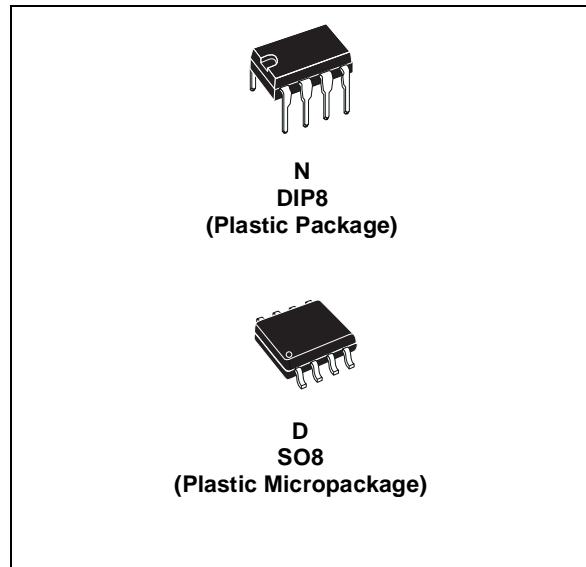
DESCRIPTION

The UA741 is a high performance monolithic operational amplifier constructed on a single silicon chip. It is intended for a wide range of analog applications.

- Summing amplifier
- Voltage follower
- Integrator
- Active filter
- Function generator

The high gain and wide range of operating voltages provide superior performances in integrator, summing amplifier and general feedback applications. The internal compensation network (6dB/octave) insures stability in closed loop circuits.

PIN CONNECTIONS (top view)



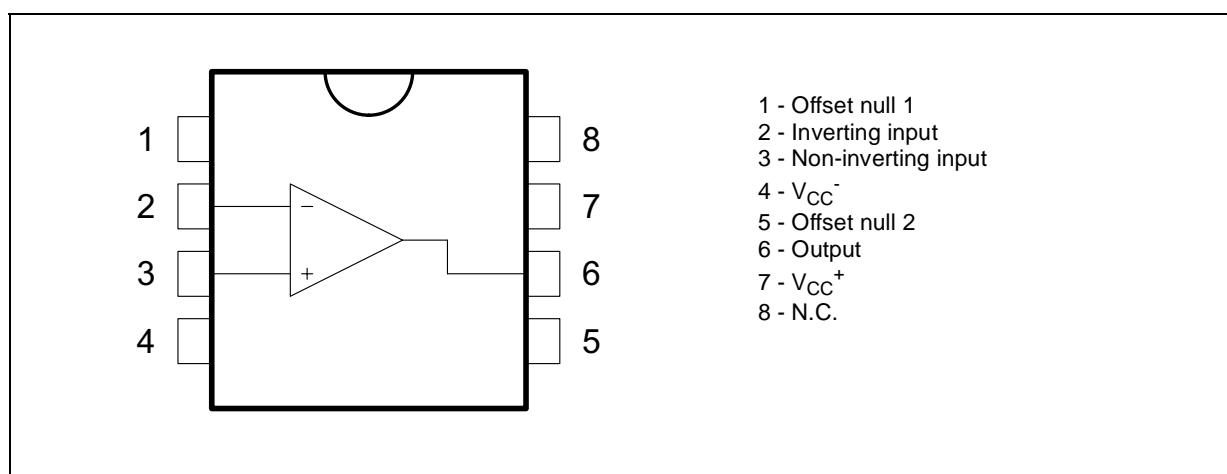
ORDER CODE

Part Number	Temperature Range	Package	
		N	D
UA741C	0°C, +70°C	•	•
UA741I	-40°C, +105°C	•	•
UA741M	-55°C, +125°C	•	•

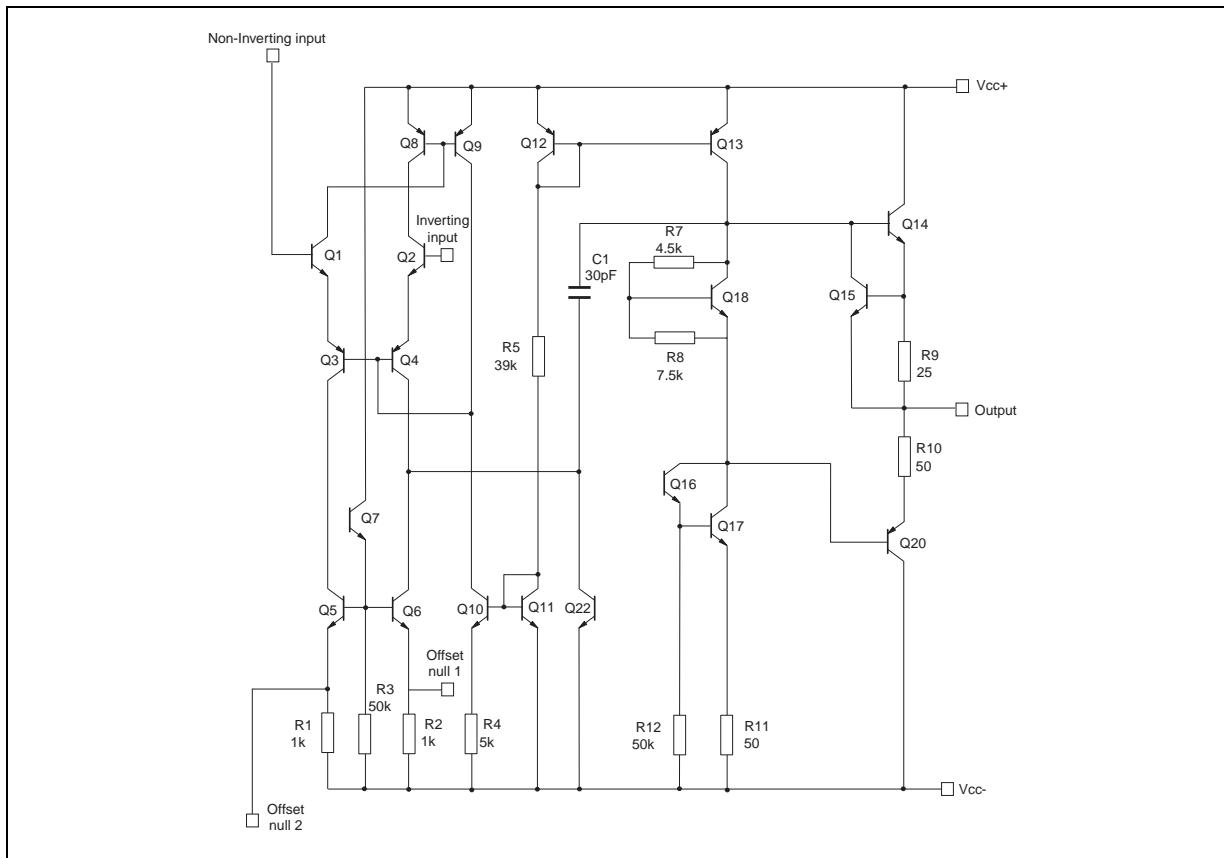
Example : UA741CN

N = Dual in Line Package (DIP)

D = Small Outline Package (SO) - also available in Tape & Reel (DT)



SCHEMATIC DIAGRAM



ABSOLUTE MAXIMUM RATINGS

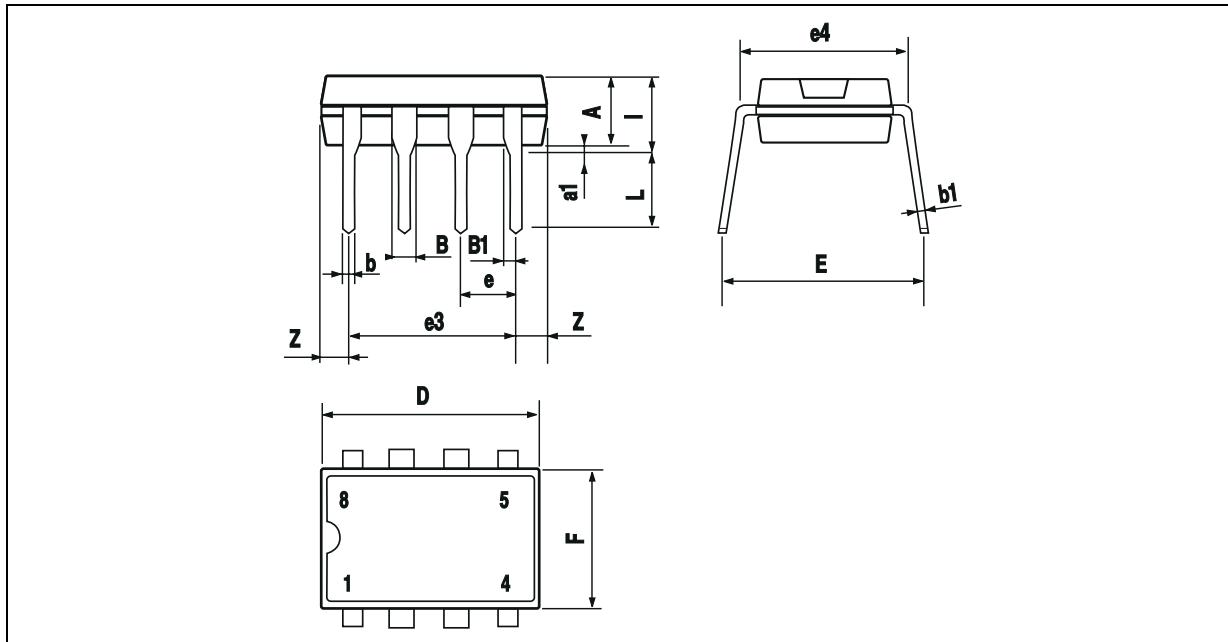
Symbol	Parameter	UA741M	UA741I	UA741C	Unit
V_{CC}	Supply voltage	± 22			V
V_{id}	Differential Input Voltage	± 30			V
V_i	Input Voltage	± 15			V
P_{tot}	Power Dissipation ¹⁾	500			mW
	Output Short-circuit Duration	Infinite			
T_{oper}	Operating Free-air Temperature Range	-55 to +125	-40 to +105	0 to +70	°C
T_{stg}	Storage Temperature Range	-65 to +150			°C

1. Power dissipation must be considered to ensure maximum junction temperature (T_j) is not exceeded.

ELECTRICAL CHARACTERISTICS $V_{CC} = \pm 15V, T_{amb} = +25^\circ C$ (unless otherwise specified)

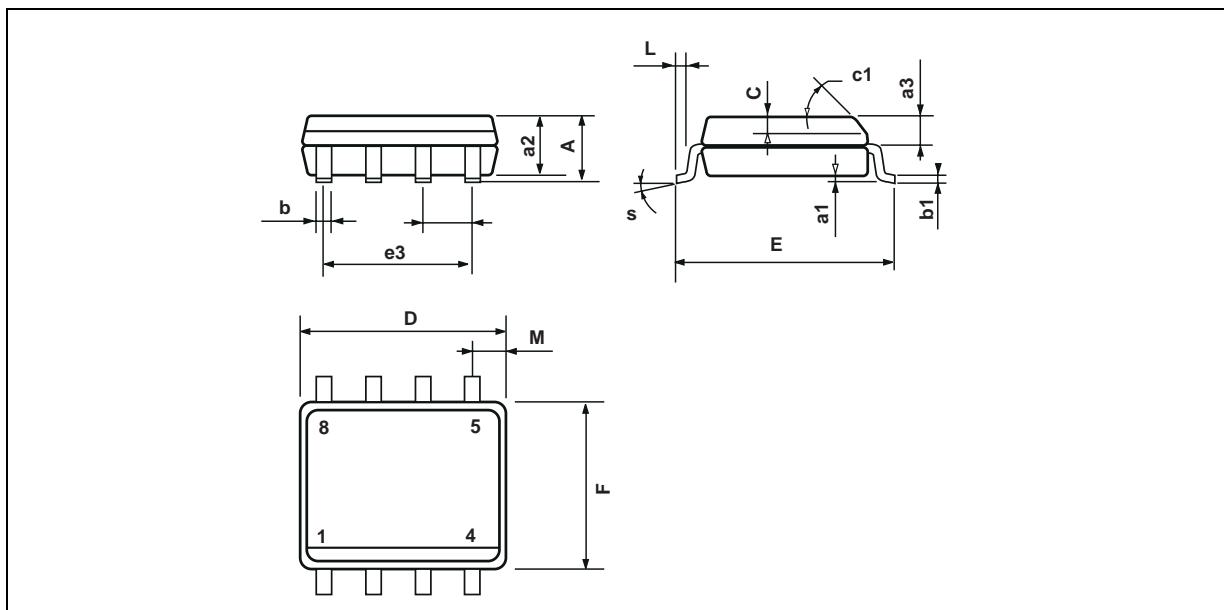
Symbol	Parameter	Min.	Typ.	Max.	Unit
V_{io}	Input Offset Voltage ($R_s \leq 10k\Omega$) $T_{amb} = +25^\circ C$ $T_{min} \leq T_{amb} \leq T_{max}$		1 5 6		mV
I_{io}	Input Offset Current $T_{amb} = +25^\circ C$ $T_{min} \leq T_{amb} \leq T_{max}$		2 30 70		nA
I_{ib}	Input Bias Current $T_{amb} = +25^\circ C$ $T_{min} \leq T_{amb} \leq T_{max}$		10 100 200		nA
A_{vd}	Large Signal Voltage Gain ($V_o = \pm 10V, R_L = 2k\Omega$) $T_{amb} = +25^\circ C$ $T_{min} \leq T_{amb} \leq T_{max}$	50 25	200		V/mV
SVR	Supply Voltage Rejection Ratio ($R_s \leq 10k\Omega$) $T_{amb} = +25^\circ C$ $T_{min} \leq T_{amb} \leq T_{max}$	77 77	90		dB
I_{cc}	Supply Current, no load $T_{amb} = +25^\circ C$ $T_{min} \leq T_{amb} \leq T_{max}$		1.7 2.8 3.3		mA
V_{icm}	Input Common Mode Voltage Range $T_{amb} = +25^\circ C$ $T_{min} \leq T_{amb} \leq T_{max}$	± 12 ± 12			V
CMR	Common Mode Rejection Ratio ($R_s \leq 10k\Omega$) $T_{amb} = +25^\circ C$ $T_{min} \leq T_{amb} \leq T_{max}$	70 70	90		dB
I_{os}	Output short Circuit Current	10	25	40	mA
$\pm V_{opp}$	Output Voltage Swing $T_{amb} = +25^\circ C$ $R_L = 10k\Omega$ $R_L = 2k\Omega$ $T_{min} \leq T_{amb} \leq T_{max}$ $R_L = 10k\Omega$ $R_L = 2k\Omega$	12 10 12 10	14 13		V
SR	Slew Rate $V_i = \pm 10V, R_L = 2k\Omega, C_L = 100pF$, unity Gain	0.25	0.5		V/ μ s
t_r	Rise Time $V_i = \pm 20mV, R_L = 2k\Omega, C_L = 100pF$, unity Gain		0.3		μ s
K_{ov}	Overshoot $V_i = 20mV, R_L = 2k\Omega, C_L = 100pF$, unity Gain		5		%
R_i	Input Resistance	0.3	2		M Ω
GBP	Gain Bandwidth Product $V_i = 10mV, R_L = 2k\Omega, C_L = 100pF, f = 100kHz$	0.7	1		MHz
THD	Total Harmonic Distortion $f = 1kHz, A_v = 20dB, R_L = 2k\Omega, V_o = 2V_{pp}, C_L = 100pF, T_{amb} = +25^\circ C$		0.06		%
e_n	Equivalent Input Noise Voltage $f = 1kHz, R_s = 100\Omega$		23		$\frac{nV}{\sqrt{Hz}}$
$\emptyset m$	Phase Margin		50		Degrees

PACKAGE MECHANICAL DATA
8 PINS - PLASTIC DIP



Dim.	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A		3.32			0.131	
a1	0.51			0.020		
B	1.15		1.65	0.045		0.065
b	0.356		0.55	0.014		0.022
b1	0.204		0.304	0.008		0.012
D			10.92			0.430
E	7.95		9.75	0.313		0.384
e		2.54			0.100	
e3		7.62			0.300	
e4		7.62			0.300	
F			6.6			0.260
i			5.08			0.200
L	3.18		3.81	0.125		0.150
Z			1.52			0.060

PACKAGE MECHANICAL DATA
8 PINS - PLASTIC MICROPACKAGE (SO)



Dim.	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			1.75			0.069
a1	0.1		0.25	0.004		0.010
a2			1.65			0.065
a3	0.65		0.85	0.026		0.033
b	0.35		0.48	0.014		0.019
b1	0.19		0.25	0.007		0.010
C	0.25		0.5	0.010		0.020
c1	45° (typ.)					
D	4.8		5.0	0.189		0.197
E	5.8		6.2	0.228		0.244
e		1.27			0.050	
e3		3.81			0.150	
F	3.8		4.0	0.150		0.157
L	0.4		1.27	0.016		0.050
M			0.6			0.024
S	8° (max.)					

Information furnished is believed to be accurate and reliable. However, STMicroelectronics assumes no responsibility for the consequences of use of such information nor for any infringement of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of STMicroelectronics. Specifications mentioned in this publication are subject to change without notice. This publication supersedes and replaces all information previously supplied. STMicroelectronics products are not authorized for use as critical components in life support devices or systems without express written approval of STMicroelectronics.

© The ST logo is a registered trademark of STMicroelectronics

© 2001 STMicroelectronics - Printed in Italy - All Rights Reserved
STMicroelectronics GROUP OF COMPANIES

Australia - Brazil - Canada - China - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan - Malaysia
Malta - Morocco - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States

© <http://www.st.com>